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An Inductive Self-complementary Hilbert-curve Antenna for UHF RFID Tags

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1. Introduction

Recently there has been a rapidly growing interest in RFID systems and its applications. Operating frequencies including 125 KHz–134 KHz and 140 KHz–148.5 KHz LF band, 13.56 MHz HF band and 868 MHz–960 MHz UHF band were applied to various supply chains. 433 MHz band was decided for active reader and 2.45 GHz band was applied for WiFi reader. Besides the reader antennas, the requirements of tag antennas are necessary for applications. In which, due to the benefit of long read range and low cost, the UHF tag will be used as the system of distribution and logistics around the world [1–13], [29–41]. Meander line antennas were commonly for UHF tags, due to the characteristics of high gain, omni-directionality, planarity and relatively small surface size [5]. However, the length-to-width ratio limited as 5:1 was proposed [2]. Recently, the half-Sierpinski fractal antenna was introduced with a small length-to-width ratio (<2:1) [11]. Meanwhile, the inductive impedance of tag antenna was necessary for matching the capacitive terminations of chip IC, thus the tuning apparatus was proposed [4], [8]–[10]. H-shaped meandered-slot antennas with the performance of broadband and conjugate impedance matching were developed for on-body applications [14], [15]. On the other hand, the self-complementary dipoles were introduced for the performance of wideband, high impedance and balun [16]–[23].

The Hilbert-curve, proposed by Hilbert and introduced by Peano [24], was known as the space-filling curves. The structure of this shape can be made of a long metallic wire compacted within a patch. As the iteration order of the curve increases, the Hilbert-curve can be space-filling the patch. It has been used in fractal antenna with size reduction [25–28], [44–52].

The main aim of this paper is to merge the meander line and meandered-slot structure of the RFID tag antenna in order to obtain a good performance of compact, broadband and conjugate impedance matching. Meantime, demonstrating the performance with a self-complementary Hilbert-curve tag antenna is proposed. The self-complementary Hilbert-curve tag antenna is constructed with substrate, Hilbert-curve, Hilbert-curve slot and tuning pad. For circular polarization analysis, the current distribution and electric field are exhibited. The inductive and broadband characteristics of frequency responses and directivity feature of radiation patterns and polarization are studied and presented.
2. Antenna configuration and basis

2.1 UFH RFID meander-line antenna
The typical dipole antenna consists of two parts, in Fig.1, one is the dipole resonators with half-wavelength for resonance and the other is the balun for the impedance transfer of balance to unbalance terminations. The standing voltage and current distribute among the dipole with maxima current and minimum voltage feeding in the center (0°) for linear polarization. For size reduction, in Fig.2, the meander-line configuration was applied in tag antenna. By tuning load-line structure, more wideband and inductive performance can be achieved.

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![Fig. 1. Dipole antenna](image1)

![Fig. 2. Meander line antennas](image2)

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2.2 Hilbert-curve and space filling
Hilbert-curve is a space filling curve with being self-similar and simple geometry. The configurations of Hilbert-curve for first four fractal iterations are shown in Figure 3. The original space has filling nature of these curves. This expresses that for a given area of a space, the total length of the line segments increase progressively as the iteration order increases. It can be interpreted as the cause for their relatively lower resonant frequency. It is evident that the fractal iteration order increases, the total length of the line segments
increases, even as the area it encompasses remain the same. Thus within a small area, a lower resonant frequency antenna with very large line length can be accommodated. In applications, the structure of this shape can be made of a long metallic wire compacted within a microstrip patch.

The topological dimension of the line segments is one, as it consists only of a line. The dimension of this original space is an integer value equated two. When we consider the length and number of line segments with 2\textsuperscript{nd}, 3\textsuperscript{rd} and 4\textsuperscript{th} iterations, this dimension are 1.465, 1.694 and 1.834. These values point to the fact the geometry has fractional dimension. As the dimension approaches 2, the curve almost fills a space. In other words, for large iteration orders, the total length of the line segments tends to be extremely large. This could be a significant advantage in lower frequency antenna design since the overall effective length of the antenna is large. Thus the resonant frequency can be reduced considerably for a given area, by increasing the fractal iteration order. It may result in a larger reduction factor for the antenna size.

![Fig. 3. First four fractal iterations for the Hilbert-curve configurations, (a) original space (b) 1\textsuperscript{st} iterations (c) 2\textsuperscript{nd} iterations (d) 3\textsuperscript{rd} iterations (e) 4\textsuperscript{th} iterations](image-url)

### 2.3 Self-complementary antennas
Self-complementary antenna composed with electric and magnetic pair antennas is a potential antenna solution for multi-band and wide-band antenna system because of its excellent isolation performance at close proximity between antennas. The pair antennas can be configured with log-period, spiral and circular disk configuration depends on application shown in Fig. 4.

Antenna pair with self-complementary structure has a constant input impedance, independent of the source frequency and the antenna geometry. To achieve wideband CP performance, self-complementary structures were commonly used owing to their features of simple feeding and good axial ratio [17, 18, 23].

### 2.4 Self-complementary Hilbert-curve tag antenna
Complementary Hilbert-curve tag antenna is constructed with substrate, Hilbert-curve, Hilbert-curve slot and tuning pad ($L_t$) in Fig. 5. The Hilbert-curve is consisted of three series Hilbert-curve with the 3rd iteration. The dimensions are $L_1 = 23.5$ mm, $L_2 = 24$ mm, $L_3 = 5$ mm, $W_1 = 7.5$ mm, $W_2 = 8.5$ mm, $W_3 = 0.75$ mm, $W_4 = 0.5$ mm, and $g = 0.35$ mm. The thickness ($h$) of RT/duroid-6010 substrate is 6.35 mm (1.27mm×5) and the relative permittivity $\varepsilon_r$ is 10.2 shown in Fig. 6. The length-to-width ratio is 6.2:1 and the shortening ratio $SR=0.69$. The reduction is notable when the SR is more than 0.40 [2].
A typical circular polarization dipole cross-pair usually consist of two individuals with horizontal and vertical locations, and a two-phase signal with 90° difference. Fig. 7 illustrates the simulated current distributions and Fig. 6 depicts the simulated electric fields among the planar structures, which provide a clearly physical insight on understanding the circular polarization of the proposed antenna. Fig. 5 shows that the Hilbert-curve is excited...
with concentrating current distributions at the 900 MHz resonance while the maximum amplitude located at \(-11.3^\circ\) with deviation from central feed-line (0°). The Hilbert-curve slot is expressed with lower current distributions. Fig. 8 presents both Hilbert-curve line and Hilbert-curve slot are excited with intensive electric fields at the 900 MHz resonance while the minimum amplitude presented at \(-22.5^\circ\).

Fig. 5. Complementary Hilbert-curve antenna

Since the phase difference with 33.8° among maximum current amplitude and minimum electric field existed, in company with the different locations of the left Hilbert-curve line and the right Hilbert-curve slot, the elliptic polarization will be obtained. Thus, the circular polarization can be observed along a certain direction.

Fig. 6. Dimensions of complementary Hilbert-curve tag antenna
2.5 Applications

The maximum activation distance of the tag for the given frequency is given [14]–[15] by

\[
d_{\text{max}} = \frac{c}{4\pi f} \sqrt{\frac{\text{EIRP}_R}{P_{\text{chip}}}} \tau G
\]

(1)

Where \( \text{EIRP}_R \) is the effective transmitted power of reader, \( P_{\text{chip}} \) is the sensitivity of tag microchip, \( G \) is the maximum tag antenna gain, and the power transmission factor

\[
\tau = \frac{4R_{\text{chip}} R_A}{\left| X_{\text{chip}} + X_A \right|^2} \leq 1
\]

(2)

with tag antenna impedance \( Z_A = R_A + jX_A \) and microchip impedance \( Z_{\text{chip}} = R_{\text{chip}} + jX_{\text{chip}} \).

3. Simulations and experiments

By using the commercial software of HFSS tool [42], the simulation results included return loss spectrums, impedance spectrum, circular polarization and two-cut radiation patterns are presented and analyzed. For comparison, the return loss spectrums of the proposed antenna with UHF-bands of 900 MHz are measured and simulated shown in Fig. 9.

The simulated and measured results of frequency responses are in agreement. In measurement, while the return loss is smaller than -10dB, the frequency responses cover both Europe 865.6–867.6 MHz band and USA 902–928 MHz band, ranging from 820 to 935 MHz (bandwidth = 115 MHz). For applications, the frequency responses are fully applied in the operation bands of the RFID UHF-band. For impedance spectrum analysis in Fig. 10, it shows the real parts of impedance become maximum value (178.7 Ω) at 970 MHz frequency,
the real parts of impedance value (102.5 \( \Omega \)) and the imaginary parts of impedance present inductive characteristic (+41.3 \( \Omega \)) at 900 MHz frequency. The inductive impedance can be available for matching the capacitive RFID chip.

Fig. 9. Simulated and measured results of return loss spectrum

Fig. 10. Simulated results of impedance spectrum

The radiation patterns are obtained by an automatic measurement system in an anechoic chamber. The under-tested antenna is located on the X-Y plane shown in Fig. 4, and the feeding line is located along the X-axis. Thus, two radiation patterns with Y-Z cut and X-Z cut are obtained.
The two cut patterns with resonant 900 MHz are represented in Fig. 11 respectively. Broadside patterns are observed in the Y-Z cut and quasi-omnidirectional patterns are obtained in the X-Z cut. The measured maximum gain was 1.68 dBi for 900 MHz. For polarizations, the AR spectrum is presented in Fig. 12. The minimum AR with 0.16 at $\phi = 0^\circ$, $\theta = 90^\circ$ and the right-hand circular polarizations ($-3$dB AR BW = 383 MHz) are observed along the direction of the $\phi$ and $\theta$, thus the proposed antenna can be applied to circular polarization applications which represents one of the availability and usefulness in contrast to the conventional meander-line and meander-slot tags.

Fig. 11. Radiation patterns for 900 MHz

Fig. 12. AR spectrum

4. Conjugate matching performance

For example, the effective transmitted power $EIRP_r$ of reader is 1W, the sensitivity $P_{chip}$ of tag microchip is -10dBm, the maximum tag antenna gain $G = 1.62$ dBi, and the activation
distance $d_{\text{min/max}} = 2.5/3$ m, the power transmission factor can be obtained $\tau = 0.73/0.87$ by using (2). Then, from (3) and tag antenna impedance ($Z_A = 102.5+j41.3$ $\Omega$), the microchip impedance ($Z_{\text{chip}} = 14.7-j45.2$ $\Omega$) is calculated. For 900 MHz signal, the capacitance (757 pf) of the chip microchip is presented.

For applications, the variation in antenna impedance, microchip impedance and tuning pad ($L_t = 1.0, 2.0, 3.0, 4.0$ and $5.0$ mm) is shown in Table I. The varied inductive impedance can be available for matching the related capacitive RFID chip (564–787 pf) by tuning the pad length.

<table>
<thead>
<tr>
<th>$L_t$ (mm)</th>
<th>$Z_A$ ($\Omega$)</th>
<th>$G_{\text{max}}$ (dB)</th>
<th>$d_{\text{min/max}}$ (m)</th>
<th>$\tau_{\text{min/max}}$</th>
<th>$Z_{\text{chip}}$ ($\Omega$)</th>
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</thead>
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<tr>
<td>1</td>
<td>97.8+j46.3</td>
<td>0.98</td>
<td>2.5/3</td>
<td>0.71/0.96</td>
<td>15.6-j46.4</td>
</tr>
<tr>
<td>2</td>
<td>98.7+j45.6</td>
<td>1.12</td>
<td>2.5/3</td>
<td>0.68/0.99</td>
<td>14.3-j45.5</td>
</tr>
<tr>
<td>3</td>
<td>97.3+j44.2</td>
<td>1.21</td>
<td>2.5/3</td>
<td>0.78/0.98</td>
<td>15.7-j44.3</td>
</tr>
<tr>
<td>4</td>
<td>99.6+j43.4</td>
<td>1.38</td>
<td>2.5/3</td>
<td>0.76/0.93</td>
<td>14.2-j45.8</td>
</tr>
<tr>
<td>5</td>
<td>102.5+j41.3</td>
<td>1.62</td>
<td>2.5/3</td>
<td>0.73/0.87</td>
<td>14.7-j45.2</td>
</tr>
</tbody>
</table>

Table 1. Variation results

A microchip, RI-UHF-STRAP-08 of TI, is used for applications [43]. The data sheet is presented in Table 2. The diagram of complex plane $Z(\omega)$ is presented in Fig. 13. The microchip impedance locus $Z_{\text{chip}}(\omega)$ is firstly plotted in the complex plane. The arrowhead attached to the locus indicates the direction of increasing $\omega$ from 860 to 960 MHz. Then, tuning the length, as $g=0.45$ mm, $L_f = 5.8$ mm and $L_t = 6.3$ mm, the antenna impedance locus $Z_A(\omega)$ is obtained. The intersection of these two loci corresponds to the operating point. Due to the operating point $Z_A = 287+j55$ $\Omega$ and $Z_{\text{chip}} = 287-j55$ $\Omega$, $\tau = 0.54$ is calculated by (2). As $EIRP = 1$W, $P_{\text{chip}} = -13$dBm and $G = 1.62$dB, $d_{\text{max}} = 33$ m is obtained by (1).
PART NUMBER  |  RI-UHF-STRAP-08
---|---

**Absolute Maximum Ratings**

<table>
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<th>NOTES</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
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<tr>
<td>Input current, pad to pad</td>
<td>1</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td>Input voltage to any pad (sustained)</td>
<td>1.5</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Power dissipation</td>
<td>TA = 25°C</td>
<td>1.5</td>
<td>mW</td>
</tr>
<tr>
<td>Storage temperature range</td>
<td>Single Strap</td>
<td>-40</td>
<td>85</td>
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<tr>
<td></td>
<td>On Reel</td>
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<td>45</td>
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<tr>
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<td>Read</td>
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<td>65</td>
</tr>
<tr>
<td></td>
<td>Write</td>
<td>-25</td>
<td>65</td>
</tr>
<tr>
<td>Assembly survival temperature</td>
<td>1 minute maximum</td>
<td>150</td>
<td>°C</td>
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<tr>
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<td>800 ~ 1000 MHz</td>
<td>10</td>
<td>dBm</td>
</tr>
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<td>ESD immunity</td>
<td>Charged-Device Model (CDM)</td>
<td>0.5</td>
<td>kv</td>
</tr>
<tr>
<td></td>
<td>Human-Body Model (HBM)</td>
<td>2</td>
<td>kv</td>
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**Recommended Operating Conditions**

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<tr>
<td>TA Operating temperature</td>
<td>-40</td>
<td>65</td>
<td>°C</td>
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<tr>
<td>f\text{res} Carrier frequency</td>
<td>860</td>
<td>960</td>
<td>MHz</td>
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**Electrical Characteristics**

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<th>Typ</th>
<th>Unit</th>
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<td>Reading</td>
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<td>-13</td>
<td>dBm</td>
</tr>
<tr>
<td></td>
<td>Programming</td>
<td>-6/-</td>
<td>-19</td>
<td>dBm</td>
</tr>
<tr>
<td>ΔΓ Change in modulator reflection coefficient</td>
<td></td>
<td></td>
<td>&gt;0.2</td>
<td></td>
</tr>
<tr>
<td>t\text{DRET} Data retention</td>
<td>10/-</td>
<td>Years</td>
<td></td>
<td></td>
</tr>
<tr>
<td>W&amp;E Write and erase endurance</td>
<td>100000/-</td>
<td>Cycles</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Strap Parallel Impedance</td>
<td>Typical Read (-13 dB)</td>
<td>380</td>
<td>Ω</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>2.8</td>
<td>pF</td>
<td></td>
</tr>
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</table>

Table 2. Specification of microchip RI-UHF-STRAP-08

For deterministic design, the design procedure is stated as: The guided wavelength ($\lambda_g / 2$) of the central frequency determines the total length of series Hilbert-curve. The desired response and impedance are then tuned by $L_t$. The final tuning is with $g$. Using (1) and (2) with the specifications and boundary condition $d_{1/2}$, the $Z_{chip}$ is obtained. If it is not satisfied, retuning $L_t$ and $g$ till the desired value is achieved.

5. Conclusion

The self-complementary antenna with Hilbert-curve configuration for RFID UHF-band tags is presented in this paper. The good performance of compact, broadband (BW=150 MHz), circular polarization and conjugate impedance matching are achieved for applications. The
structure is smaller in size and easy to fabricate in tag circuits. Its operations cover UHF-bands 820 to 935 MHz for return loss < -10dB. Both simulation and measurement results are agreed with the verified frequency responses. The inductive impedance is achieved and be available for matching the capacitive RFID chip.

In field analysis, broadside patterns are observed in the Y-Z cut and quasi-omnidirectional patterns are obtained in the X-Z cut. The measured maximum gain was 1.68 dBi for 900 MHz. The circular polarization (-3dB AR BW = 383 MHz) feature of radiation patterns for 900 MHz are presented. It is a compact and available tag antenna for UHF RFID applications.

6. References


Radio Frequency Identification (RFID) is a modern wireless data transmission and reception technique for applications including automatic identification, asset tracking and security surveillance. This book focuses on the advances in RFID tag antenna and ASIC design, novel chipless RFID tag design, security protocol enhancements along with some novel applications of RFID.

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